

Green Products

Description

The SMP1008 includes back-to-back TVS diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (\pm 15kV contact discharge) without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.

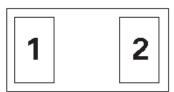
Features

- ESD protection in accordance with:
 IEC 61000-4-2 (ESD) ±15kV (air), ±15kV (contact)
 IEC 61000-4-5 (lightning) 2.5A (8/20µs)
 IEC 61000-4-4 (EFT) 40A (5/50ns)
- Low capacitance of 6 pF @ VR=5V
- Low leakage current of 0.1µA at 5V
- Space efficient 0201 footprint

Applications

- Mobile Phones
- MP3/PMP
- Portable Medical
- Camcorders
- Smart Phones
- eReaders/eBooks
- Tablets
- Digital Cameras

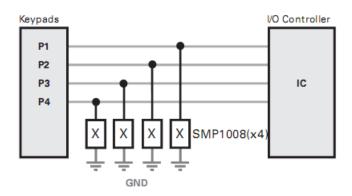
Pinout







HDMI Application Example



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Ordering Information:

Device	Package	Marking	Min. Order Qty.	
SMP1008-01WTG	0201 Flipship	X	10000	

Absolute Maximum Ratings:

Parameter	Symbol	Value	Unit
Peak Pulse Current (tp=8/20µs)	IPP	2.5	Α
Operating Temperature	Тор	-40 to + 85	°C
Storage Temperature	Tstor	-60 to + 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information:

Parameter	Value	Unit
Storage Temperature Range	-65 to + 150	°C
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 20-40s)	260	°C

Electrical Characteristics: (T_{OP}=25°C)

Characteristics	Symbol	Condition	Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage	V_{RWM}	-	-	-	6.0	V
Breakdown Voltage	V_{BR}	$I_R = 1mA$	-	7.0	8.5	V
Reverse Leakage Current	I _{LEAK}	V _R =5V with 1pin at GND	-	0.1	-	μA
Clamping Voltage ¹	V _C	I _{PP} = 1A, tp=8/20μs, Fwd	-	10.7	-	V
	V C	I _{PP} = 2A, tp=8/20μs, Fwd		12.0	-	V
ESD With stand Voltage ¹		IEC61000-4-2	±15	-	-	kV
	V _{ESD}	(Contact Discharge)				
		IEC61000-4-2	± 15	-	-	kV
		(Air Discharge)				
Dynamic Resistance	R_{DYN}	(V _{C2} -V _{C1})/(I _{PP2} -I _{PP1})	-	1.3	-	Ω
Junction Capacitance ¹		Reverse Bias=0V	-	9	-	pF
C _D		Reverse Bias=5.0V	-	6	9	

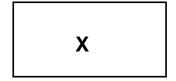
Note: 1. Parameter is guaranteed by design and/or device characterization.

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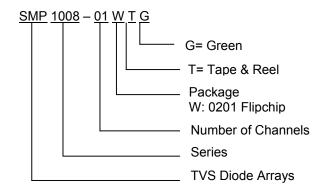


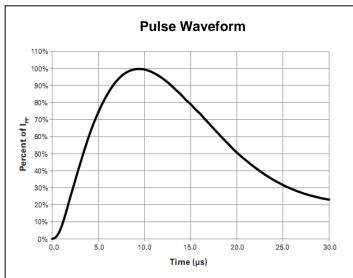
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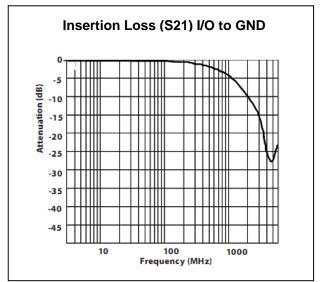
Marking Diagram

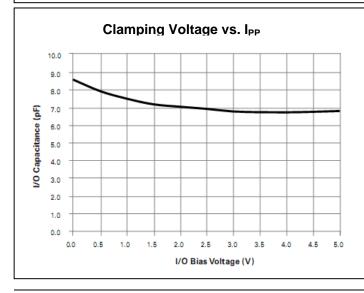


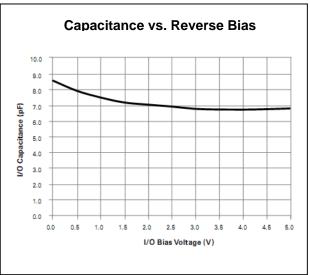
Part Name Information









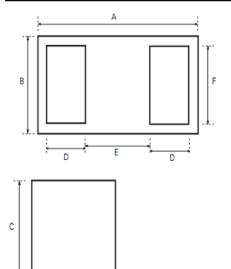


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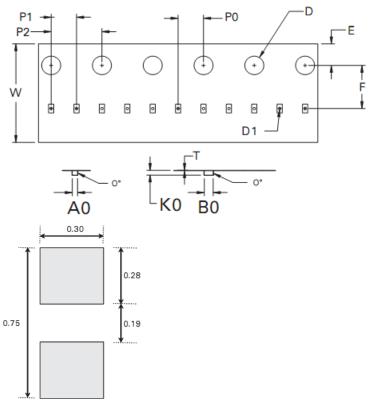
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Mechanical Dimensions (In mm/Inches):



	0201 Flipchip					
Symbol	Millimeters		Inches			
	Min	Тур	Max	Min	Тур	Max
Α	0.595	0.620	0.645	0.0234	0.0244	0.0254
В	0.295	0.320	0.345	0.0116	0.0126	0.0136
С	0.245	0.275	0.305	0.0096	0.0108	0.0120
D	0.145	0.150	0.155	0.0057	0.0059	0.0061
E	0.245	0.250	0.255	0.0096	0.0098	0.0100
F	0.245	0.250	0.255	0.0096	0.0098	0.0100
G	0.005	0.010	0.015	0.0002	0.0004	0.0006

Embossed Carrier Tape & Reel Speciication — 0201 Flipchip



Symbol	Millimeters	
Α0	0.41+/-0.03	
В0	0.70+/-0.03	
D	Ф 1.50 + 0.10	
D1	Ф 0.20 +/- 0.05	
E	1.75+/-0.10	
F	3.50+/-0.05	
K0	0.38+/-0.03	
P0	2.00+/-0.05	
P1	2.00+/-0.05	
P2	4.00+/-0.10	
W	8.00+0.30/-0.10	
Т	0.23+/-0.02	

Recommended Solder Pad Footprint

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